



A Product Line of Diodes Incorporated



## 25V PNP LOW SATURATION TRANSISTOR IN SOT23

#### Features

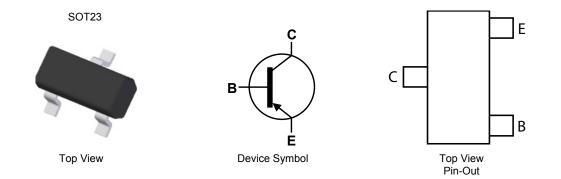
- BV<sub>CEO</sub> > -25V
- BV<sub>CEO</sub> > -35V forward blocking voltage
- I<sub>C</sub> = -3A Continuous Collector Current
- Low Saturation Voltage, V<sub>CE(SAT)</sub> < -150mV @ -1A.</li>
- R<sub>CE(sat)</sub> = 87mΩ for a low equivalent on-resistance
- 725mW power dissipation
- h<sub>FE</sub> characterised up to -6A for high current gain hold-up
- Complementary NPN Type: ZXTN649F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(63)</sup>
- Weight 0.008 grams (approximate)

## Application

- MOSFET gate drivers
- Power switching in automotive and industrial applications
- Motor drive and control



#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP749FTA	1N8	7	8	3,000

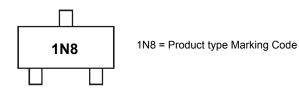
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com

## **Marking Information**







### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-35	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-25	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ιc	-3	A
Peak Pulse Current	I <sub>CM</sub>	-6	A
Base Current	Ι <sub>Β</sub>	-500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

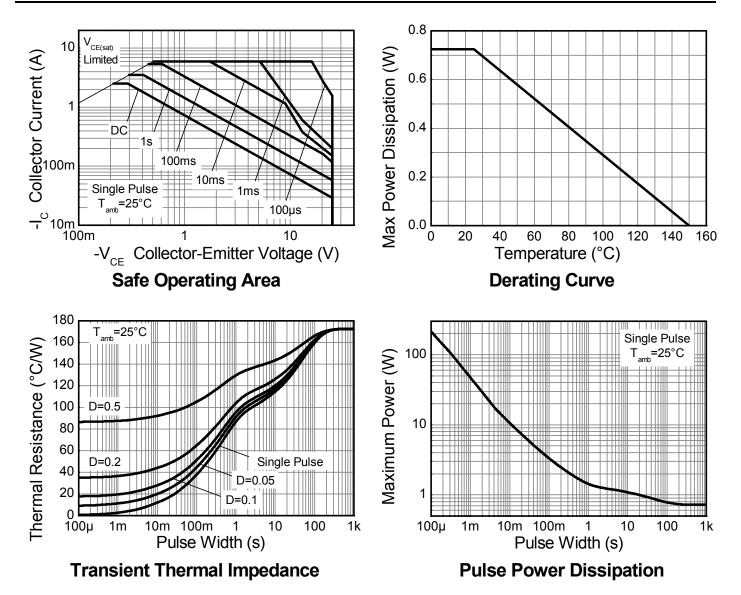
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	725	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	172	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R <sub>θJL</sub>	79	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

Notes: 5. For a device surface mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition. 6. Thermal resistance from junction to solder-point (at the end of the collector lead).





## Thermal Characteristics and Derating information







# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

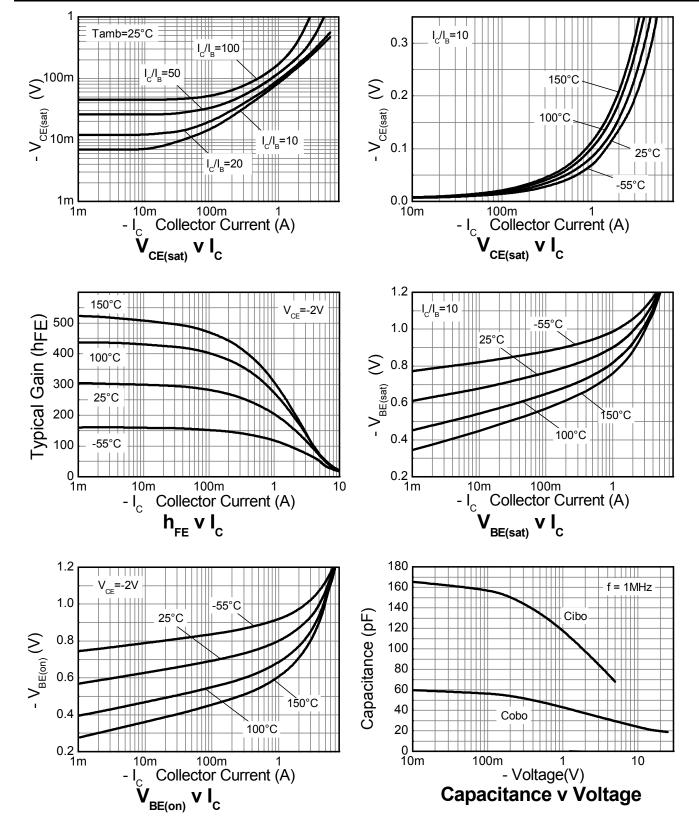
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-35	-60	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-25	-40	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.4	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	<1	-50 -0.5	nA μA	V <sub>CB</sub> = -28V V <sub>CB</sub> = -28V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-50	nA	V <sub>EB</sub> = -5.6V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	200 130 100 25	320 230 180 50	500 - - -	-	$I_{C} = -100 \text{mA}, V_{CE} = -2V$ $I_{C} = -1A, V_{CE} = -2V$ $I_{C} = -2A, V_{CE} = -2V$ $I_{C} = -6A, V_{CE} = -2V$
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	-	-85 -229	-150 -350	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	-	-786	-850	mV	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	-	-895	-1000	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA

7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2% Notes:



FT FX







Тур

0.40

1.30

2.40

0.915

0.535

1.83

2.90

0.05

1.00

0.400

0.55

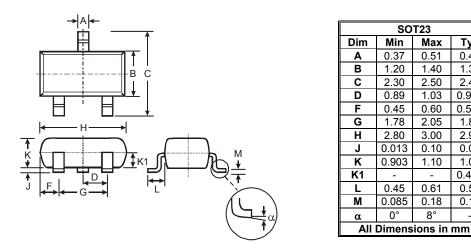
0.11



ſΕΧ

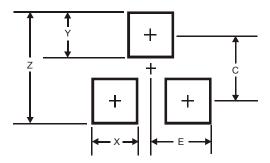
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





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